NSN 5961-01-111-5662

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-111-5662 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Terminal Length:** 0.980 inches **Overall Diameter:** Between 0.046 inches and 0.056 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 repetitive peak reverse voltage, peak total value and 50.0 working peak reverse voltage **Current Rating Per Characteristic:** 100.00 amperes source cutoff current peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No